## Uncompensated, High Slew Rate Operational Amplifier

The HA-2520/883 is a monolithic operational amplifier which delivers an unsurpassed combination of specifications for slew rate, bandwidth and settling time. This dielectrically isolated amplifier is designed for closed loop gains of 3 or greater without external compensation. In addition, this high performance component also provides low offset current and high input impedance.

The $100 \mathrm{~V} / \mu \mathrm{s}(\mathrm{min})$ slew rate and fast settling time of this amplifier make it ideal for pulse amplification and data acquisition designs. To insure compliance with slew rate and transient response specifications, the device is $100 \%$ tested for AC performance characteristics over full temperature. This device is a valuable component for RF and video circuitry requiring wideband operation. For accurate signal conditioning designs, the HA-2520/883's superior dynamic specifications are complemented by 25 nA (max) offset current and offset voltage adjust capability.

Part Number Information

| PART <br> NUMBER | TEMP. RANGE <br> $\left({ }^{\circ} \mathrm{C}\right)$ | PACKAGE | PKG. NO. |
| :---: | :---: | :---: | :---: |
| HA2-2520/883 | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8 Pin Can | T8.C |

## Applications

- Data Acquisition Systems
- RF Amplifiers
- Video Amplifiers
- Signal Generators
- Pulse Amplification


## Features

- This Circuit is Processed in Accordance to MIL-STD-883 and is Fully Conformant Under the Provisions of Paragraph 1.2.1.
- High Slew Rate . . . . . . . . . . . . . . . . . . . . . . 100V/ $\mu \mathrm{s}$ (Min) 120V/ $\mu \mathrm{s}$ (Min)
- Wide Power Bandwidth . . . . . . . . . . . . . . . . 1.5MHz (Min)
- Wide Gain Bandwidth. . . . . . . . . . . . . . . . . . . 10MHz (Min) 20MHz (Typ)
- High Input Impedance . . . . . . . . . . . . . . . . . . 50M $\Omega$ (Min) $100 \mathrm{M} \Omega$ (Тур)
- Low Offset Current . . . . . . . . . . . . . . . . . . . . . . 25nA (Min) 10nA (Typ)
- Fast Settling (0.1\% of 10V Step) . . . . . . . . . . 200ns (Typ)
- Low Quiescent Supply Current . . . . . . . . . . . . 6mA (Max)


## Pinout



## Absolute Maximum Ratings

Voltage Between V+ and V- Terminals . . . . . . . . . . . . . . . . . . . . 40V
Differential Input Voltage . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 15 V
Voltage at Either Input Terminal . . . . . . . . . . . . . . . . . . . . . V+ to V-
Peak Output Current . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 50mA
Junction Temperature . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $+175^{\circ} \mathrm{C}$
Storage Temperature Range . . . . . . . . . . . . . . . . . $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
ESD Rating . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $<2000 \mathrm{~V}$
Lead Temperature (Soldering 10s) . . . . . . . . . . . . . . . . . . . . $+300^{\circ} \mathrm{C}$

## Operating Conditions

Operating Temperature Range . . . . . . . . . . . . . . . $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
Operating Supply Voltage.
. . . . . . . . . . . . . . . . . . . . . . . . . . . . . $\pm 15 \mathrm{~V}$
CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.
NOTE:

1. $\theta_{J A}$ is measured with the component mounted on a low effective thermal conductivity test board in free air. See Tech Brief TB379 for details.

TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS
Device Tested at: $\mathrm{V}_{\text {SUPPLY }}= \pm 15 \mathrm{~V}$, RSOURCE $=100 \Omega$, R LOAD $=500 \mathrm{k} \Omega$, $\mathrm{V}_{\text {OUT }}=0 \mathrm{~V}$, Unless Otherwise Specified.

| PARAMETERS | SYMBOL | CONDITIONS | GROUP A SUBGROUPS | TEMPERATURE | HA-2520/883 |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | MIN | MAX |  |
| Input Offset Voltage | $\mathrm{V}_{10}$ | $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V}$ | 1 | $+25^{\circ} \mathrm{C}$ | -8 | 8 | mV |
|  |  |  | 2, 3 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | -10 | 10 | mV |
| Input Bias Current | ${ }^{+1}{ }_{B}$ | $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V},+\mathrm{R}_{\mathrm{S}}=100 \mathrm{k} \Omega,-\mathrm{R}_{\mathrm{S}}=100 \Omega$ | 1 | $+25^{\circ} \mathrm{C}$ | -200 | 200 | nA |
|  |  |  | 2, 3 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | -400 | 400 | nA |
|  | ${ }^{-1} B$ | $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V},+\mathrm{R}_{\mathrm{S}}=100 \Omega,-\mathrm{R}_{\mathrm{S}}=100 \mathrm{k} \Omega$ | 1 | $+25^{\circ} \mathrm{C}$ | -200 | 200 | nA |
|  |  |  | 2, 3 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | -400 | 400 | nA |
| Input Offset Current | IIO | $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V},+\mathrm{R}_{\mathrm{S}}=100 \mathrm{k} \Omega,-\mathrm{R}_{\mathrm{S}}=100 \mathrm{k} \Omega$ | 1 | $+25^{\circ} \mathrm{C}$ | -25 | 25 | nA |
|  |  |  | 2, 3 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | -50 | 50 | nA |
| Common Mode Range | +CMR | $\mathrm{V}+=5 \mathrm{~V}, \mathrm{~V}-=-25 \mathrm{~V}$ | 1 | $+25^{\circ} \mathrm{C}$ | +10 | - | V |
|  |  |  | 2, 3 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | +10 | - | V |
|  | -CMR | $\mathrm{V}+=25 \mathrm{~V}, \mathrm{~V}-=-5 \mathrm{~V}$ | 1 | $+25^{\circ} \mathrm{C}$ | - | -10 | V |
|  |  |  | 2, 3 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | - | -10 | V |
| Large Signal Voltage Gain | +AVOL | $\mathrm{V}_{\text {OUT }}=0 \mathrm{~V}$ and $+10 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ | 4 | $+25^{\circ} \mathrm{C}$ | 10 | - | kV/V |
|  |  |  | 5, 6 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | 7.5 | - | kV/V |
|  | -Avol | $\mathrm{V}_{\text {OUT }}=0 \mathrm{~V}$ and $-10 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ | 4 | $+25^{\circ} \mathrm{C}$ | 10 | - | kV/V |
|  |  |  | 5, 6 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | 7.5 | - | kV/V |
| Common Mode Rejection Ratio | +CMRR | $\begin{aligned} & \Delta \mathrm{V}_{\mathrm{CM}}=+10 \mathrm{~V}, \mathrm{~V}+=+5 \mathrm{~V}, \mathrm{~V}-=-25 \mathrm{~V}, \\ & \mathrm{~V}_{\text {OUT }}=-10 \mathrm{~V} \end{aligned}$ | 1 | $+25^{\circ} \mathrm{C}$ | 80 | - | dB |
|  |  |  | 2, 3 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | 80 | - | dB |
|  | -CMRR | $\begin{aligned} & \Delta \mathrm{V}_{\mathrm{CM}}=-10 \mathrm{~V}, \mathrm{~V}+=+25 \mathrm{~V}, \mathrm{~V}-=-5 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{OUT}}=+10 \mathrm{~V} \end{aligned}$ | 1 | $+25^{\circ} \mathrm{C}$ | 80 | - | dB |
|  |  |  | 2, 3 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | 80 | - | dB |
| Output Voltage Swing | +V ${ }_{\text {OUT }}$ | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ | 4 | $+25^{\circ} \mathrm{C}$ | 10 | - | V |
|  |  |  | 5, 6 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | 10 | - | V |
|  | - $\mathrm{V}_{\text {OUT }}$ | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ | 4 | $+25^{\circ} \mathrm{C}$ | - | -10 | V |
|  |  |  | 5, 6 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | - | -10 | V |

TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS (Continued)
Device Tested at: $\mathrm{V}_{\text {SUPPLY }}= \pm 15 \mathrm{~V}, \mathrm{R}_{\text {SOURCE }}=100 \Omega, \mathrm{R}_{\text {LOAD }}=500 \mathrm{k} \Omega, \mathrm{V}_{\text {OUT }}=0 \mathrm{~V}$, Unless Otherwise Specified.

| PARAMETERS | SYMBOL | CONDITIONS | GROUP A SUBGROUPS | TEMPERATURE | HA-2520/883 |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | MIN | MAX |  |
| Output Current | +lout | $V_{\text {OUT }}=-10 \mathrm{~V}$ | 4 | $+25^{\circ} \mathrm{C}$ | 10 | - | mA |
|  |  |  | 5,6 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | 7.5 | - | mA |
|  | -Iout | $\mathrm{V}_{\text {OUT }}=+10 \mathrm{~V}$ | 4 | $+25^{\circ} \mathrm{C}$ | - | -10 | mA |
|  |  |  | 5, 6 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | - | -7.5 | mA |
| Quiescent Power Supply Current | ${ }^{+} \mathrm{ICC}$ | $\mathrm{V}_{\text {OUT }}=0 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=0 \mathrm{~mA}$ | 1 | $+25^{\circ} \mathrm{C}$ | - | 6 | mA |
|  |  |  | 2, 3 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | - | 6.5 | mA |
|  | ${ }^{-1} \mathrm{Cc}$ | $\mathrm{V}_{\text {OUT }}=0 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=0 \mathrm{~mA}$ | 1 | $+25^{\circ} \mathrm{C}$ | -6 | - | mA |
|  |  |  | 2, 3 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | -6.5 | - | mA |
| Power Supply Rejection Ratio | +PSRR | $\begin{aligned} & \Delta \mathrm{V}_{\text {SUP }}=10 \mathrm{~V}, \mathrm{~V}_{+}=+20 \mathrm{~V}, \mathrm{~V}-=-15 \mathrm{~V}, \mathrm{~V}+ \\ & =+10 \mathrm{~V}, \mathrm{~V}-=-15 \mathrm{~V} \end{aligned}$ | 1 | $+25^{\circ} \mathrm{C}$ | 80 | - | dB |
|  |  |  | 2, 3 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | 80 | - | dB |
|  | -PSRR | $\begin{aligned} & \Delta \mathrm{V}_{\text {SUP }}=10 \mathrm{~V}, \mathrm{~V}+=+15 \mathrm{~V}, \mathrm{~V}-=-20 \mathrm{~V}, \mathrm{~V}+ \\ & =+15 \mathrm{~V}, \mathrm{~V}-=-10 \mathrm{~V} \end{aligned}$ | 1 | $+25^{\circ} \mathrm{C}$ | 80 | - | dB |
|  |  |  | 2, 3 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | 80 | - | dB |
| Offset Voltage Adjustment | $+\mathrm{V}_{10} \mathrm{Adj}$ | Note 1 | 1 | $+25^{\circ} \mathrm{C}$ | $\mathrm{V}_{10-1}$ | - | mV |
|  |  |  | 2, 3 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | $\mathrm{V}_{10}-1$ | - | mV |
|  | $-\mathrm{V}_{10} \mathrm{Adj}$ | Note 1 | 1 | $+25^{\circ} \mathrm{C}$ | $\mathrm{V}_{10}+1$ | - | mV |
|  |  |  | 2, 3 | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | $\mathrm{V}_{1 \mathrm{O}^{+1}}$ | - | mV |

NOTE:
2. Offset adjustment range is $\left[\mathrm{V}_{\mathrm{IO}}\right.$ (Measured) $\left.\pm 1 \mathrm{mV}\right]$ minimum referred to output. This test is for functionality only to assure adjustment through 0 V .

TABLE 2. AC ELECTRICAL PERFORMANCE CHARACTERISTICS
Device Tested at: $V_{\text {SUPPLY }}= \pm 15 \mathrm{~V}$, $\mathrm{R}_{\text {SOURCE }}=50 \Omega, \mathrm{R}_{\text {LOAD }}=2 \mathrm{k} \Omega, \mathrm{C}_{\text {LOAD }}=50 \mathrm{pF}, \mathrm{A}_{\mathrm{VCL}}=+3 \mathrm{~V} / \mathrm{V}$, Unless Otherwise Specified.

| PARAMETERS | SYMBOL | CONDITIONS | GROUP A SUBGROUPS | TEMPERATURE | HA-2520/883 |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | MIN | MAX |  |
| Slew Rate | +SR | $\mathrm{V}_{\text {OUT }}=-5 \mathrm{~V}$ to $+5 \mathrm{~V}, 25 \% \leq+\mathrm{SR} \leq 75 \%$ | 7 | $+25^{\circ} \mathrm{C}$ | 100 | - | V/us |
|  |  |  | 8A, 8B | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | 84 | - | V/us |
|  | -SR | $\mathrm{V}_{\text {OUT }}=+5 \mathrm{~V}$ to -5V, $75 \% \geq-\mathrm{SR} \geq 25 \%$ | 7 | $+25^{\circ} \mathrm{C}$ | 100 | - | $\mathrm{V} / \mathrm{\mu s}$ |
|  |  |  | 8A, 8B | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | 84 | - | $\mathrm{V} / \mathrm{\mu s}$ |
| Rise and Fall Time | $\mathrm{T}_{\mathrm{R}}$ | $\mathrm{V}_{\text {OUT }}=0$ to $+200 \mathrm{mV}, 10 \% \leq \mathrm{T}_{\mathrm{R}} \leq 90 \%$ | 7 | $+25^{\circ} \mathrm{C}$ | - | 50 | ns |
|  |  |  | 8A, 8B | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | - | 55 | ns |
|  | $\mathrm{T}_{\mathrm{F}}$ | $\mathrm{V}_{\text {OUT }}=0$ to -200mV, $10 \% \leq \mathrm{T}_{\mathrm{F}} \leq 90 \%$ | 7 | $+25^{\circ} \mathrm{C}$ | - | 50 | ns |
|  |  |  | 8A, 8B | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | - | 55 | ns |
| Overshoot | +OS | $\mathrm{V}_{\text {OUT }}=0$ to +200 mV | 7 | $+25^{\circ} \mathrm{C}$ | - | 40 | \% |
|  |  |  | 8A, 8B | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | - | 45 | \% |
|  | -OS | $\mathrm{V}_{\text {OUT }}=0$ to -200 mV | 7 | $+25^{\circ} \mathrm{C}$ | - | 40 | \% |
|  |  |  | 8A, 8B | $+125^{\circ} \mathrm{C},-55^{\circ} \mathrm{C}$ | - | 45 | \% |

TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS
Device Characterized at: $V_{\text {SUPPLY }}= \pm 15 \mathrm{~V}, R_{\text {LOAD }}=2 k \Omega, C_{\text {LOAD }}=50 \mathrm{pF}, A_{V} \geq 3, C_{C O M P}=0 p F$, Unless Otherwise Specified.

| PARAMETERS | SYMBOL | CONDITIONS | NOTES | TEMPERATURE | HA-2520/883 |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | MIN | MAX |  |
| Differential Input Resistance | $\mathrm{R}_{\text {IN }}$ | $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V}$ | 1 | $+25^{\circ} \mathrm{C}$ | 50 | - | $\mathrm{M} \Omega$ |
| Full Power Bandwidth | GBWP | $\mathrm{V}_{\mathrm{O}}=200 \mathrm{mV}$, $\mathrm{f}_{\mathrm{O}}=10 \mathrm{kHz}$ | 1 | $+25^{\circ} \mathrm{C}$ | 10 | - | MHz |
|  |  | $\mathrm{V}_{\mathrm{O}}=200 \mathrm{mV}, \mathrm{f}_{\mathrm{O}}=1 \mathrm{MHz}$ | 1 | $+25^{\circ} \mathrm{C}$ | 10 | - | MHz |
| Full Power Bandwidth | FPBW | $\mathrm{V}_{\text {PEAK }}=10 \mathrm{~V}$ | 1, 2 | $+25^{\circ} \mathrm{C}$ | 1.6 | - | MHz |
| Minimum Closed Loop Stable Gain | CLSG | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ | 1 | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | +3 | - | V/V |
| Quiescent Power Consumption | PC | $\mathrm{V}_{\text {OUT }}=0 \mathrm{~V}, \mathrm{I}$ OUT $=0 \mathrm{~mA}$ | 1, 3 | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | - | 195 | mW |

NOTES:
3. Parameters listed in Table 3 are controlled via design or process parameters and are not directly tested at final production. These parameters are lab characterized upon initial design release, or upon design changes. These parameters are guaranteed by characterization based upon data from multiple production runs which reflect lot to lot and within lot variation.
4. Full Power Bandwidth guarantee based on Slew Rate measurement using FPBW = Slew Rate/( $2 \pi \mathrm{~V}_{\text {PEAK }}$ ).
5. Quiescent Power Consumption based upon Quiescent Supply Current test maximum. (No load on outputs.)

TABLE 4. ELECTRICAL TEST REQUIREMENTS

| MIL-STD-883 TEST REQUIREMENTS | SUBGROUPS (SEE TABLES 1 AND 2) |
| :--- | :---: |
| Interim Electrical Parameters (Pre Burn-In) | 1 |
| Final Electrical Test Parameters | 1 (Note 4), 2, 3, 4, 5, 6, 7, 8A, 8B |
| Group A Test Requirements | $1,2,3,4,5,6,7,8 \mathrm{~A}, 8 \mathrm{~B}$ |
| Groups C and D Endpoints | 1 |

NOTE:
6. PDA applies to Subgroup 1 only.

## Die Characteristics

DIE DIMENSIONS:
$67 \times 57 \times 19$ mils $\pm 1$ mils $1700 \times 1440 \times 483 \mu \mathrm{~m} \pm 25.4 \mu \mathrm{~m}$

## METALLIZATION:

Type: AI, 1\% Cu
Thickness: $16 \mathrm{k} \AA \pm 2 k \AA$

## GLASSIVATION:

Type: Nitride (Si3N4) over Silox (SiO2, 5\% Phos.)
Silox Thickness: $12 k \AA \pm 2 k \AA$
Nitride Thickness: $3.5 \mathrm{k} \AA \pm 1.5 \mathrm{k} \AA$

## WORST CASE CURRENT DENSITY:

$0.26 \times 10^{5} \mathrm{~A} / \mathrm{cm}^{2}$
SUBSTRATE POTENTIAL (Powered Up):

## Unbiased

## TRANSISTOR COUNT:

## HA-2520/883: 40

## PROCESS:

Bipolar Dielectric Isolation

## Metallization Mask Layout



Metal Can Packages (Can)


NOTES:

1. (All leads) $\varnothing b$ applies between L 1 and L2. Øb1 applies between L 2 and 0.500 from the reference plane. Diameter is uncontrolled in L1 and beyond 0.500 from the reference plane.
2. Measured from maximum diameter of the product.
3. $\alpha$ is the basic spacing from the centerline of the tab to terminal 1 and $\beta$ is the basic spacing of each lead or lead position (N-1 places) from $\alpha$, looking at the bottom of the package.
4. $N$ is the maximum number of terminal positions.
5. Dimensioning and tolerancing per ANSI Y14.5M - 1982.
6. Controlling dimension: INCH .

## T8.C mil-std 1835 MACY1-X8 (A1) 8 LEAD METAL CAN PACKAGE

| SYMBOL | INCHES |  | MILLIMETERS |  | NOTES |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN | MAX | MIN | MAX |  |
| A | 0.165 | 0.185 | 4.19 | 4.70 | - |
| Øb | 0.016 | 0.019 | 0.41 | 0.48 | 1 |
| Øb1 | 0.016 | 0.021 | 0.41 | 0.53 | 1 |
| Øb2 | 0.016 | 0.024 | 0.41 | 0.61 | - |
| $\varnothing \mathrm{D}$ | 0.335 | 0.375 | 8.51 | 9.40 | - |
| ØD1 | 0.305 | 0.335 | 7.75 | 8.51 | - |
| ØD2 | 0.110 | 0.160 | 2.79 | 4.06 | - |
| e | 0.20 | BSC |  | SC | - |
| e1 | 0.10 | BSC |  | BSC | - |
| F | - | 0.040 | - | 1.02 | - |
| k | 0.027 | 0.034 | 0.69 | 0.86 | - |
| k1 | 0.027 | 0.045 | 0.69 | 1.14 | 2 |
| L | 0.500 | 0.750 | 12.70 | 19.05 | 1 |
| L1 | - | 0.050 | - | 1.27 | 1 |
| L2 | 0.250 | - | 6.35 | - | 1 |
| Q | 0.010 | 0.045 | 0.25 | 1.14 | - |
| $\alpha$ | $45^{\circ} \mathrm{BSC}$ |  | $45^{\circ} \mathrm{BSC}$ |  | 3 |
| $\beta$ | $45^{\circ} \mathrm{BSC}$ |  | $45^{\circ} \mathrm{BSC}$ |  | 3 |
| N | 8 |  | 8 |  | 4 |

Rev. 0 5/18/94

All Intersil U.S. products are manufactured, assembled and tested utilizing ISO9000 quality systems.
Intersil Corporation's quality certifications can be viewed at www.intersil.com/design/quality

[^0]For information regarding Intersil Corporation and its products, see www.intersil.com


[^0]:    Intersil products are sold by description only. Intersil Corporation reserves the right to make changes in circuit design, software and/or specifications at any time without notice. Accordingly, the reader is cautioned to verify that data sheets are current before placing orders. Information furnished by Intersil is believed to be accurate and reliable. However, no responsibility is assumed by Intersil or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Intersil or its subsidiaries.

